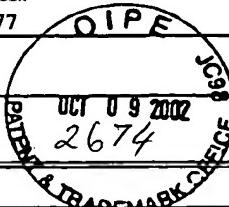


Form PTO 1449		ATTY. DOCKET NUMBER NITT.0057	SERIAL NUMBER 10/031,377
U.S. Department of Commerce Patent and Trademark Office		APPLICANT SUZUKI et al.	GROUP 2674
Information Disclosure Statement by Applicant		FILING DATE April 12, 2002	



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Examiner Initial		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE
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Kmn		2-184890	1/12/89	Japan				X
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Technology Center 2000


EXAMINER

Karen M. Nguyen

DATE CONSIDERED

3/10/2006

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10/031377  
JC13 Rec'd PCT/PTO 18 JAN 2002

Form PTO 1449		ATTY. DOCKET NUMBER NITT.0057	ITEM NUMBER To Be Assigned
U.S. Department of Commerce Patent and Trademark Office		APPLICANT SUZUKI et al.	
Information Disclosure Statement by Applicant		FILING DATE Concurrently Herewith	GROUP 2674

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